

General Description

The MAX4613 quad analog switch features on-resistance matching (4 Ω max) between switches and guarantees on-resistance flatness over the signal range (9 Ω max). This low on-resistance switch conducts equally well in either direction. It guarantees low charge injection (10pC max), low power consumption (35µW max), and an electrostatic discharge (ESD) tolerance of 2000V minimum per Method 3015.7. The new design offers lower off leakage current over temperature (less than 5nA at +85°C).

The MAX4613 quad, single-pole/single-throw (SPST) analog switch has two normally closed switches and the two normally open switches. Switching times are less than 250ns for ton and less than 70ns for toff. Operation is from a single +4.5V to +40V supply or bipolar ±4.5V to ±20V supplies.

Applications

Sample-and-Hold Circuits Communication Systems Test Equipment **Battery-Operated Systems**

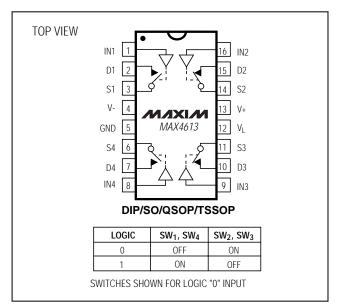
Heads-Up Displays PBX, PABX

Guidance and Control Systems Audio Signal Routing Military Radios Modems/Faxes

Features

- ♦ Pin Compatible with Industry-Standard DG213
- **♦** Guaranteed Ron Match Between Channels (4 Ω max)
- **♦** Guaranteed RFLAT(ON) Over Signal Range (9 Ω max)
- ♦ Guaranteed Charge Injection (10pC max)
- **♦ Low Off Leakage Current Over Temperature** (<5nA at +85°C)
- ♦ Withstands 2000V min ESD, per Method 3015.7
- ♦ Low R_{DS}(ON) (85 Ω max)
- ♦ Single-Supply Operation +4.5V to +40V Bipolar-Supply Operation ±4.5V to ±20V
- ♦ Low Power Consumption (35µW max)
- ♦ Rail-to-Rail® Signal Handling
- ♦ TTL/CMOS-Logic Compatible

Pin Configuration/ Functional Diagram/TruthTable



Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4613CPE	0°C to +70°C	16 Plastic DIP
MAX4613CSE	0°C to +70°C	16 Narrow SO
MAX4613CEE	0°C to +70°C	16 QSOP
MAX4613CUE	0°C to +70°C	16 TSSOP**
MAX4613C/D	0°C to +70°C	Dice*
MAX4613EPE	-40°C to +85°C	16 Plastic DIP
MAX4613ESE	-40°C to +85°C	16 Narrow SO
MAX4613EEE	-40°C to +85°C	16 QSOP
MAX4613EUE	-40°C to +85°C	16 TSSOP**

^{*}Contact factory for dice specifications.

Rail-to-Rail is a registered trademark of Nippon Motorola Ltd.

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^{**}Contact factory for availability.

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to GND	
V+	+44V
V	44V
V+ to V	+44V
VL	(GND - 0.3V) to (V+ + 0.3V)
Digital Inputs V _S V _D (Note 1)	(V 2V) to (V+ + 2V)
	or 30mA (whichever occurs first)
Continuous Current (any termina	ıl)30mA
Peak Current, S_ or D_	
(pulsed at 1ms, 10% duty cycl	e max)100mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
Plastic DIP (derate 10.53mW/°C above +70°C)	842mW
Narrow SO (derate 8.70mW/°C above +70°C)	696mW
QSOP (derate 8.3mW/°C above +70°C)	667mW
TSSOP (derate 5.7mW/°C above +70°C)	457mW
Operating Temperature Ranges	
MAX4613C	0°C to +70°C
MAX4613E4	0°C to +85°C
Storage Temperature Range65	°C to +165°C
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Signals on S_, D_, or IN_ exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

 $(V+ = 15V, V- = -15V, VL = 5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH	1						
Analog Signal Range	V _{ANALOG}	(Note 3)		-15		15	V
Drain-Source On-Resistance	Daggan	$V_D = \pm 10V$,	TA = +25°C		55	70	Ω
Dialii-Source Off-Resistance	R _{DS} (ON)	$I_S = 1mA$	TA = TMIN to TMAX			85	22
On-Resistance Match	ΔRDS(ON)	V _D = ±10V,	T _A = +25°C			4	Ω
Between Channels (Note 4)	ARDS(ON)	$I_S = 1mA$	TA = TMIN to TMAX			5	22
On Decistance Flatness (Note 4)	D= .=(0.1)	V _D = ±5V,	T _A = +25°C			9	Ω
On-Resistance Flatness (Note 4)	RFLAT(ON)	$I_S = 1mA$	TA = TMIN to TMAX			15	22
Source Leakage Current	1-4	$V_D = \pm 14V$,	T _A = +25°C	-0.50	0.01	0.50	ъ Л
(Note 5)	IS(OFF)	$V_S = \pm 14V$	TA = TMIN to TMAX	-5		5	nA
Drain-Off Leakage Current	ID(OFF)	ID(OFF) $V_D = \pm 14V,$ $V_S = \mp 14V$	T _A = +25°C	-0.50	0.01	0.50	τ. Λ
(Note 5)			TA = TMIN to TMAX	-5		5	nA
Drain-On Leakage Current	ID(ON) or IS(ON)	` ' VI) = + 4 V .	T _A = +25°C	-0.50	0.08	0.50	^
(Note 5)		$V_S = \pm 14V$	TA = TMIN to TMAX	-10		10	nA
INPUT							
Input Current with Input Voltage High	linh	V _{IN} = 2.4V, all others = 0.8V		-0.5	-0.00001	0.5	μΑ
Input Current with Input Voltage Low	linl	V _{IN} = 0.8V, all others = 2.4V		-0.5	-0.00001	0.5	μΑ
SUPPLY							
Power-Supply Range	V+, V-			±4.5		±20.0	V
Positive Supply Current	I+	All channels on or off, VIN = 0 or 5V	T _A = +25°C	-1	0.001	1	
			$T_A = T_{MIN}$ to T_{MAX}	-5		5	μΑ
Nogativo Supply Current	1	All channels on or off,	T _A = +25°C	-1	0.001	1	
Negative Supply Current	-	$V_{IN} = 0 \text{ or } 5V$ $T_A = T_{MIN} \text{ to } T_{MAX}$		-5		5	μA

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = 15V, V- = -15V, VL = 5V, GND = 0V, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDI	TIONS	MIN	TYP (Note 2)	MAX	UNITS
Lagia Cupply Current	I.	All channels on or off,	T _A = +25°C	-1	0.001	1	
Logic Supply Current	lL lL	$V_{IN} = 0 \text{ or } 5V$	TA = TMIN to TMAX	-5		5	μΑ
Ground Current	lovo	All channels on or off,	T _A = +25°C	-1	-0.0001	1	
Ground Current	IGND	$V_{IN} = 0 \text{ or } 5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		5	μΑ
DYNAMIC	•						
Turn-On Time (Note 3)	ton	$V_S = \pm 10V$, Figure 2	T _A = +25°C		150	250	ns
Turn-Off Time (Note 3)	toff	$V_S = \pm 10V$, Figure 2	TA = +25°C		90	120	ns
Break-Before-Make Time Delay (Note 3)	tD	Figure 3	TA = +25°C	5	20		ns
Charge Injection (Note 3)	Q	$C_L = 1nF$, $V_{GEN} = 0$, $R_{GEN} = 0$, Figure 4	T _A = +25°C		5	10	рС
Off-Isolation Rejection Ratio (Note 6)	OIRR	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 5	TA = +25°C		60		dB
Crosstalk (Note 7)		$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 6	T _A = +25°C		100		dB
Source-Off Capacitance	Cs(OFF)	f = 1MHz, Figure 7	$T_A = +25^{\circ}C$		4		pF
Drain-Off Capacitance	CD(OFF)	f = 1MHz, Figure 7	T _A = +25°C		4		pF
Source-On Capacitance	Cs(ON)	f = 1MHz, Figure 8	T _A = +25°C		16		pF
Drain-On Capacitance	C _{D(ON)}	f = 1MHz, Figure 8	T _A = +25°C		16		pF

ELECTRICAL CHARACTERISTICS—Single Supply $(V+=12V, V-=0V, V_L=5V, GND=0V, V_{INH}=2.4V, V_{INL}=0.8V, T_A=T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
SWITCH								
Analog Signal Range	Vanalog			0		12	V	
Drain-Source	Dog(ou)	$V_1 = 5V; V_D = 3V, 8V;$ $T_A = +25^{\circ}C$		100	160	Ω		
On-Resistance	R _{DS} (ON)	$I_S = 1mA$	TA = TMIN to TMAX			200	<u> </u>	
SUPPLY	•						•	
Power-Supply Range	V+, V-			4.5		40	V	
Power-Supply Current	1.	1+	All channels on or off,	T _A = +25°C	-1	0.001	1	μΑ
rower-supply current	1+	VIN = 0 or 5V	$T_A = T_{MIN}$ to T_{MAX}	-5		5]	
Negative Supply Current	I-	All channels on or off,	T _A = +25°C	-1	-0.0001	1		
Negative Supply Current	-	VIN = 0 or 5V	TA = TMIN to TMAX	-5		5	- μΑ	
Logio Cupply Current	1.	All channels on or off,	T _A = +25°C	-1	0.001	1		
Logic Supply Current IL	$V_{IN} = 0 \text{ or } 5V$	TA = TMIN to TMAX	-5		5	μA		
Cround Current	lave	All channels on or off,	T _A = +25°C	-1	-0.0001	1		
Ground Current IGND	$V_{IN} = 0 \text{ or } 5V$ $T_A = T_{MIN} \text{ to } T_{MAX}$	-5		5	μΑ			

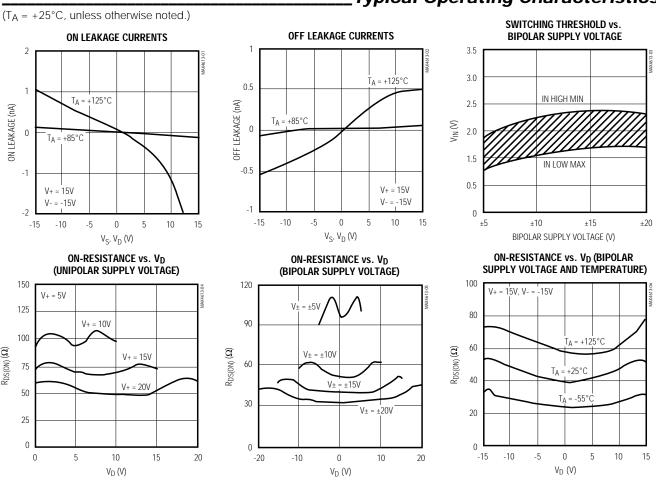
ELECTRICAL CHARACTERISTICS—Single Supply (continued)

(V+ = 12V, V- = 0, VL = 5V, GND = 0V, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
DYNAMIC							
Turn-On Time (Note 3)	ton	V _S = 8V, Figure 2	T _A = +25°C		300	400	ns
Turn-Off Time (Note 3)	toff	V _S = 8V, Figure 2	TA = +25°C		60	200	ns
Charge Injection (Note 3)	Q	$C_L = 1nF$, $V_{GEN} = 0$, $R_{GEN} = 0$, Figure 4	T _A = +25°C		5	10	рС

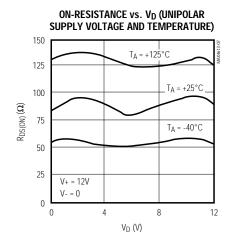
- **Note 2:** Typical values are for **design aid only,** are not guaranteed and are not subject to production testing. The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 3: Guaranteed by design.
- **Note 4:** On-resistance match between channels and flatness are guaranteed only with bipolar-supply operation. Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured at the extremes of the specified analog signal range.
- Note 5: Leakage parameters Is(OFF), ID(OFF), ID(ON), and Is(ON) are 100% tested at the maximum rated hot temperature and guaranteed at +25°C.
- Note 6: Off-Isolation Rejection Ratio = 20log (V_D/V_S).
- Note 7: Between any two switches.

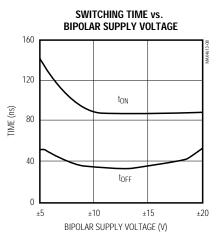
Typical Operating Characteristics

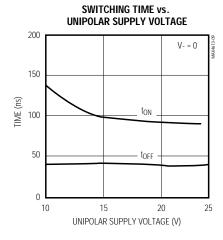


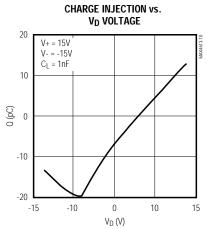
Typical Operating Characteristics (continued)

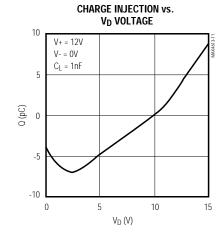
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$











Pin Description

PIN	NAME	FUNCTION
1, 16, 9, 8	IN1-IN4	Logic Control Inputs
2, 15, 10, 7	D1-D4	Drain Outputs
3, 14, 11, 6	S1-S4	Source Outputs
4	V-	Negative Supply-Voltage Input
5	GND	Ground
12	VL	Logic Supply-Voltage Input
13	V+	Positive Supply-Voltage Input—connected to substrate

Applications Information

General Operation

- 1) Switches are open when power is off.
- 2) IN_, D_, and S_ should not exceed V+ or V-, even with the power off.
- 3) Switch leakage is from each analog switch terminal to V+ or V-, not to other switch terminals.

Operation with Supply Voltages Other than ±15V

Using supply voltages less than $\pm 15V$ will reduce the analog signal range. The MAX4613 operates with $\pm 4.5V$ to $\pm 20V$ bipolar supplies or with a $\pm 4.5V$ to $\pm 40V$ single

supply; connect V- to GND when operating with a single supply. Also, all device types can operate with unbalanced supplies such as +24V and -5V. V_L must be connected to +5V to be TTL compatible, or to V+ for CMOS-logic level inputs. The *Typical Operating Characteristics* graphs show typical on-resistance with $\pm 20V$, $\pm 15V$, $\pm 10V$, and $\pm 5V$ supplies. (Switching times increase by a factor of two or more for operation at $\pm 5V$.)

Figure 1. Overvoltage Protection Using External Blocking Diodes

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by V_L, V-, and logic inputs. If power-supply sequencing is not possible, add two small, external signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and V-should not exceed +44V.

Timing Diagrams/Test Circuits

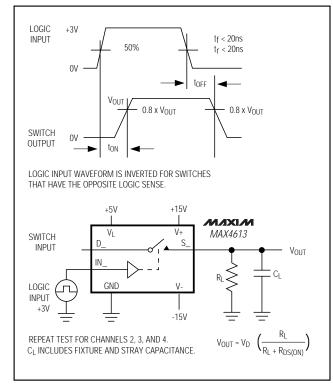


Figure 2. Switching Time

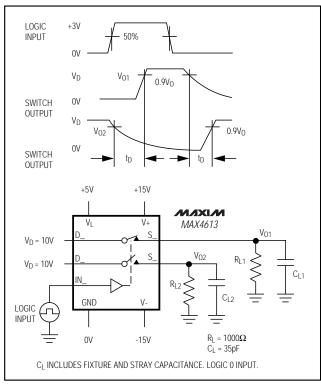


Figure 3. Break-Before-Make Test Circuit

Timing Diagrams/Test Circuits (continued)

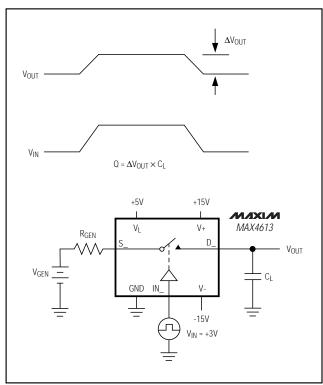


Figure 4. Charge Injection

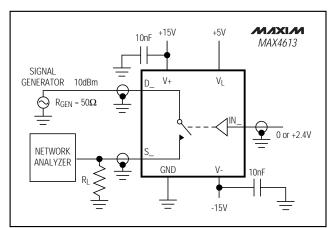


Figure 5. Off-Isolation Rejection Ratio

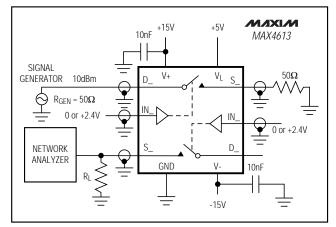


Figure 6. Crosstalk

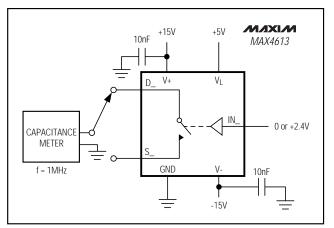


Figure 7. Source/Drain-Off Capacitance

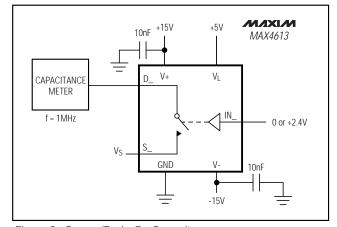
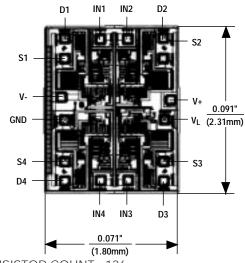


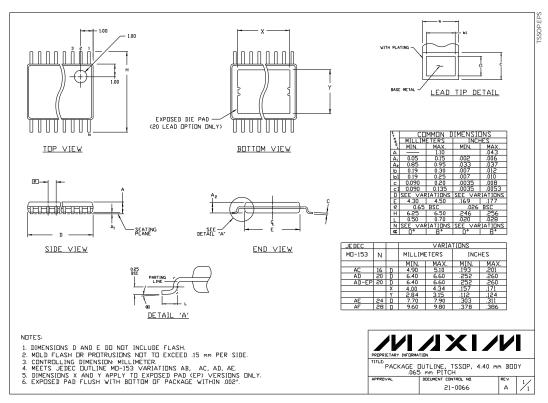
Figure 8. Source/Drain-On Capacitance

Chip Topography



TRANSISTOR COUNT: 126 SUBSTRATE CONNECTED TO V+

Package Information



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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